

2N4234
2N4235
2N4236

**SILICON
PNP TRANSISTORS**



TO-39 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N4234, 2N4235, and 2N4236 are silicon PNP transistors mounted in a hermetically sealed metal case, designed for power amplifier, power driver, and switching power supply applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	2N4234	2N4235	2N4236	UNITS
Collector-Base Voltage	V_{CBO}	40	60	80	V
Collector-Emitter Voltage	V_{CEO}	40	60	80	V
Emitter-Base Voltage	V_{EBO}		7.0		V
Continuous Collector Current	I_C		1.0		A
Peak Collector Current	I_{CM}		3.0		A
Continuous Base Current	I_B		0.2		A
Power Dissipation	P_D		6.0		W
Power Dissipation ($T_A=25^\circ\text{C}$)	P_D		1.0		W
Operating and Storage Junction Temperature	T_J, T_{stg}		-65 to +200		$^\circ\text{C}$
Thermal Resistance	θ_{JC}		29		$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=\text{Rated } V_{CBO}$		100	μA
I_{CEX}	$V_{CE}=\text{Rated } V_{CEO}, V_{BE}=1.5\text{V}$		100	μA
I_{CEX}	$V_{CE}=30\text{V}, V_{BE}=1.5\text{V}, T_C=150^\circ\text{C}$ (2N4234)		1.0	mA
I_{CEX}	$V_{CE}=40\text{V}, V_{BE}=1.5\text{V}, T_C=150^\circ\text{C}$ (2N4235)		1.0	mA
I_{CEX}	$V_{CE}=60\text{V}, V_{BE}=1.5\text{V}, T_C=150^\circ\text{C}$ (2N4236)		1.0	mA
I_{CEO}	$V_{CE}=30\text{V}$ (2N4234)		1.0	mA
I_{CEO}	$V_{CE}=40\text{V}$ (2N4235)		1.0	mA
I_{CEO}	$V_{CE}=60\text{V}$ (2N4236)		1.0	mA
I_{EBO}	$V_{EB}=7.0\text{V}$		500	μA
BV_{CEO}	$I_C=100\text{mA}$ (2N4234)	40		V
BV_{CEO}	$I_C=100\text{mA}$ (2N4235)	60		V
BV_{CEO}	$I_C=100\text{mA}$ (2N4236)	80		V
$V_{CE(\text{SAT})}$	$I_C=1.0\text{A}, I_B=125\text{mA}$		0.6	V
$V_{BE(\text{SAT})}$	$I_C=1.0\text{A}, I_B=100\text{mA}$		1.5	V
$V_{BE(\text{ON})}$	$V_{CE}=1.0\text{V}, I_C=250\text{mA}$		1.0	V

R0 (22-October 2013)

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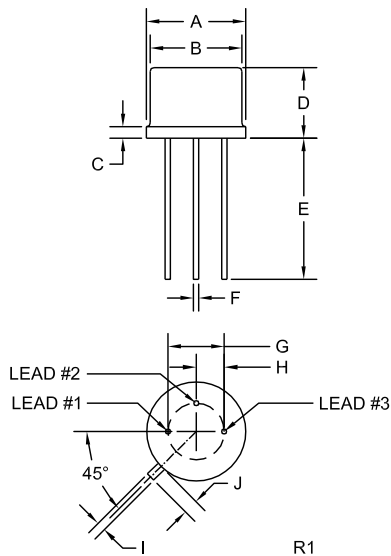
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ELECTRICAL CHARACTERISTICS - Continued: ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
h_{FE}	$V_{CE}=1.0\text{V}, I_C=100\text{mA}$	40		
h_{FE}	$V_{CE}=1.0\text{V}, I_C=250\text{mA}$	30	150	
h_{FE}	$V_{CE}=1.0\text{V}, I_C=500\text{mA}$	20		
h_{FE}	$V_{CE}=1.0\text{V}, I_C=1.0\text{A}$	10		
h_{fe}	$V_{CE}=10\text{V}, I_C=50\text{mA}, f=1.0\text{kHz}$	25		
f_T	$V_{CE}=10\text{V}, I_C=100\text{mA}, f=1.0\text{MHz}$	3.0		MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=100\text{kHz}$		100	pF

TO-39 CASE - MECHANICAL OUTLINE



DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.335	0.370	8.51	9.40
B (DIA)	0.315	0.335	8.00	8.51
C	-	0.040	-	1.02
D	0.240	0.260	6.10	6.60
E	0.500	-	12.70	-
F (DIA)	0.016	0.021	0.41	0.53
G (DIA)	0.200		5.08	
H	0.100		2.54	
I	0.028	0.034	0.71	0.86
J	0.029	0.045	0.74	1.14

TO-39 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

R0 (22-October 2013)